

Large Current External FET Controller Type Switching Regulators

Single-output Step-up, High-efficiency Switching Regulator (Controller Type)



BD9763FVM

No.09028EAT07

Description

BD9763FVM is a 1-channel high efficiency step-up switching regulator.

It is possible to choose small application space due to its high-speed operation (Max switching frequency 1.2MHz)

Features

- 1) Build-in under voltage lock out circuit.
- 2) High accuracy reference voltage ($2.5V \pm 1.0\%$)
- 3) Establish maximum duty cycle internally.
- 4) CTL/SS terminal for both stand-by and soft-start function. (Soft-start time can be set by external capacitor)
- 5) MSOP8 thin and small package.

Applications

Single-lens reflex cameras, digital video cameras, liquid crystal modules, DVD drive.

Absolute Maximum Ratings($T_a=25^\circ\text{C}$)

Parameter	Symbol	Limit	Unit
Supply voltage	Vcc	10	V
Storage temperature range	Tstg	-55 to +150	$^\circ\text{C}$
Power dissipation	Pd	587 *	mW
Junction temperature	Tjmax	+150	$^\circ\text{C}$

* IC mounted on a PCB board (70mm x 70mm x 1.6mm, glass epoxy).
Reduced by 4.7mW for each increase in T_a of 1°C over 25°C .

Recommended Operating Conditions

Parameter	Symbol	Limit			Unit
		Min	Typ	Max	
Supply voltage	Vcc	4	7	9	V
Oscillating frequency	fosc	100	-	1200	kHz
Operating temperature range	Topr	-40	-	+85	$^\circ\text{C}$

●Electrical characteristics (Unless otherwise specified, Ta=25°C, Vcc=7.0V)

Parameter	Symbol	Limits			Unit	Condition
		Min	Typ	Max		
【Oscillator】						
Oscillating frequency	fosc	522	600	678	kHz	R _{RT} =24kΩ
Frequency tolerance	FDV	-5	0	5	%	V _{cc} =4 to 9V
Swing voltage	V _{pptr}	—	0.5	—	V	
【Stand-by, Soft start】						
CTL/SS pin source current	ISS	-1.90	-1.00	-0.55	μA	V _{CTL/SS} =1.5V
CTL/SS pin clamp voltage	VSS	2.2	2.4	2.6	V	
CTL threshold voltage	V _{CTLTH}	1.2	1.3	1.4	V	
【PWM comparator】						
0% threshold voltage	D0	1.5	1.6	1.7	V	
Maximum duty cycle	D _{MAX}	80	90	99.5	%	
【Error amplifier】						
Threshold voltage	V _{IN}	0.98	1.00	1.02	V	
Band width	BW	—	3.0	—	MHz	A _V =0dB
Voltage gain	A _v	—	70	—	dB	
Input bias current	I _{IB}	-150	-70	—	nA	
Maximum output voltage	V _{CH}	2.3	2.4	2.6	V	
Minimum output current	V _{CL}	—	0.03	0.20	V	
Output source current	I _{OI}	-3.1	-1.6	-1.0	mA	V _{FB} =1.0V
Output sink current	I _{OO}	12	50	125	mA	V _{FB} =1.0V
【Reference voltage】						
Output voltage	V _{REF}	2.475	2.500	2.525	V	I _{VREF} =0mA
Load regulation	ΔV _{REFIo}	-	-	10	mV	I _{VREF} =0 to -1mA
Output short current	I _{VREF}	-45	-16	-1	mA	
【Whole device】						
Stand-by current	I _{CCS}	420	610	960	μA	
Circuit current	I _{CCA}	3.4	5.0	7.8	mA	No load
【Output】						
ON resistance	R _{ON}	0.9	2.5	8.0	Ω	
Output rise/fall time	T _r /T _f	—	20	—	nsec	C _{out} =1000pF
Output source current	I _{OUTSO}	—	-0.80	—	A	T _a =-40 to 85℃,V _{CC} =4 to 9V, OUT=0V, rush current
Output sink current	I _{OUTSI}	—	0.85	—	A	T _a =-40 to 85℃,V _{CC} =4 to 9V, OUT=V _{CC} , rush current
【Under voltage lock out】						
Threshold voltage	V _{UT}	3.7	3.8	3.9	V	V _{cc} sweep down
Hysteresis width	V _{UTHy}	0.05	0.10	0.15	V	

●Reference data (Unless otherwise specified, Ta=25°C)

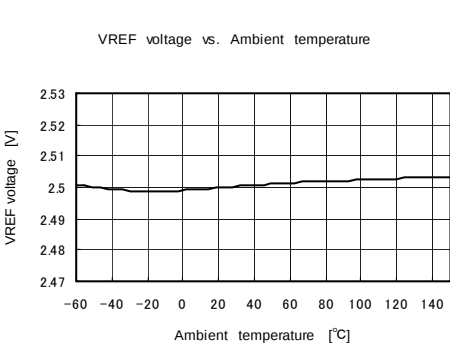


Fig.1 VREF voltage – Ambient temperature

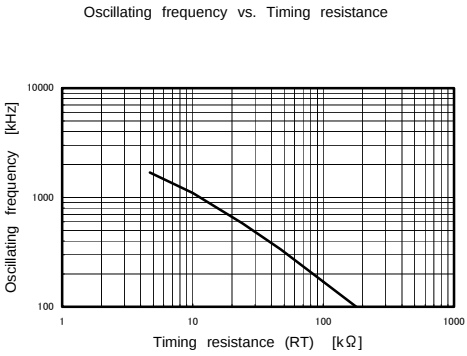


Fig.2 Oscillating frequency – Timing resistance (R_{RT})

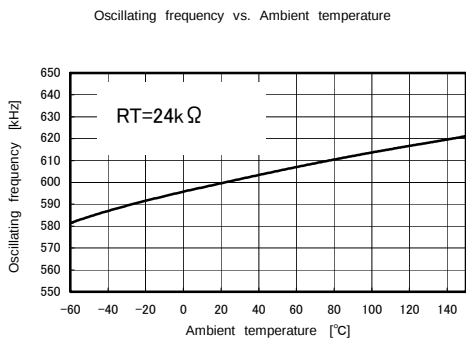


Fig.3 Oscillating frequency – Ambient temperature
(RT=24kΩ)

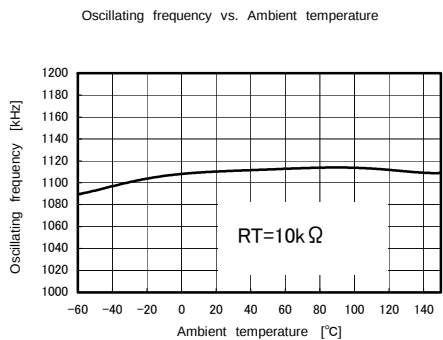


Fig.4 Oscillating frequency – Ambient temperature
(RT=10kΩ)

●Block diagram

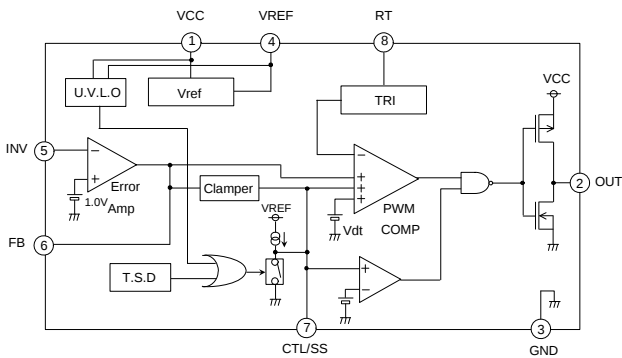


Fig.5

●Pin configuration

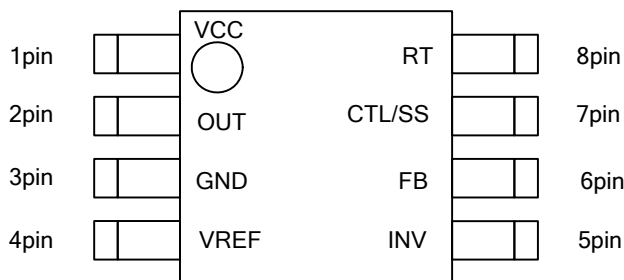


Fig.6

●Pin number , Pin name

Pin No.	Pin name	Function
1	VCC	Power supply
2	OUT	FET driver output
3	GND	Ground
4	VREF	Reference voltage ($2.5V \pm 1\%$) output
5	INV	Inverting input of error amplifier
6	FB	Output of error amplifier
7	CTL/SS	Stand-by switch/Soft start capacitor connecting pin
8	RT	Timing resistor connecting pin

●Block description

• VOLTAGE REFERENCE(VREF) BLOCK

This voltage reference block generates 2.5V internal reference voltage.

• OSCILLATOR BLOCK

Oscillator block sets the oscillating frequency adjusted by an external resistance in RT pin. The oscillating frequency can be set within a range of 100~1200kHz.. (See the description of how to set the frequency on page6.)

• PWM COMP

The PWM comparator transforms the voltage outputted from error amp to PWM waveform and outputs to FET driver. The maximum duty cycle is limited up to 90%.

• ERROR AMP BLOCK

The error amp block detects the output voltage from the INV pin, amplifies the difference between the detected voltage and the reference voltage, and outputs it to FB pin. The reference voltage is $1V \pm 2\%$.

• PROTECTION CIRCUIT BLOCK

The under voltage lock out circuit is activated to shut down the whole circuit when the VCC voltage is up to 3.8V. When the thermal shutdown circuit detects abnormal heating of the chip (150°C), the output becomes off. And the output turns back on when the chip temperature goes down to a specific level.

●Application example

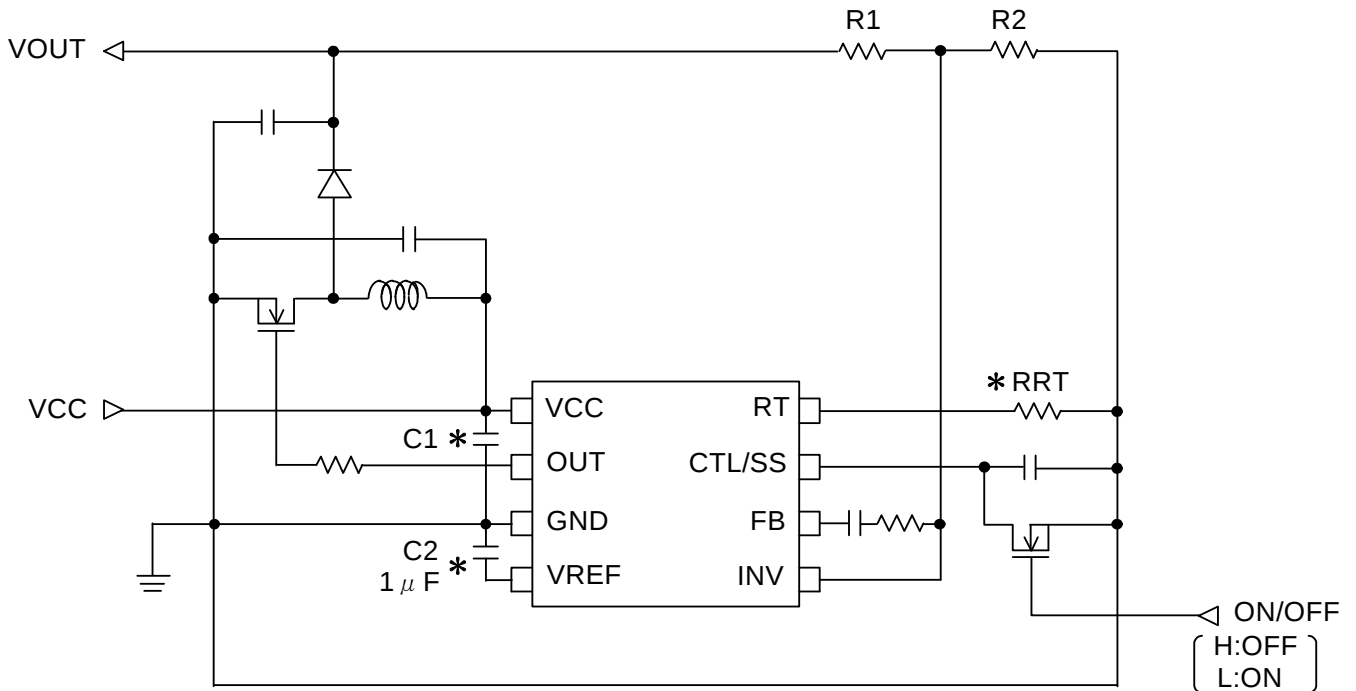


Fig.7

●Selecting application components

(1) Output inductor

It is recommended to use an inductor which satisfies the following rating current (the following value of current), and also has low DCR. The shield type inductor is preferable.

$$I_{\text{peak}} = I_o \cdot (V_o / V_{\text{IN}}) / \eta + V_{\text{IN}} \cdot (V_{\text{OUT}} - V_{\text{IN}}) / (2 \cdot V_{\text{OUT}} \cdot L \cdot f) \quad [\text{A}]$$

[I_o : Output V_o : Output voltage V_{IN} : Input voltage η : Efficiency L : Inductance f : Oscillating frequency]

(2) Output capacitor

It is recommended to use the output capacitor which has the enough margin to maximum rating for output voltage and low fluctuation for temperature. The ripple voltage of the output is influenced by ESR of the output capacitor.

$$V_{\text{ripple}} = V_{\text{IN}} \cdot (V_{\text{OUT}} - V_{\text{IN}}) / (V_{\text{OUT}} \cdot L \cdot f) \cdot \text{ESR} \quad [\text{V}]$$

$$(f \gg 1 / (2 \pi \sqrt{LC}) \cdot V_o / V_{\text{IN}})$$

[I_o : Output V_o : Output voltage V_{IN} : Input voltage η : Efficiency L : Inductance C : Output capacitor f : Oscillating frequency]

(3) FET

It is recommended to use FETs which satisfy followings and have small C_{iss} or Q_g and ON resistance.

D-S Voltage : Over (Output voltage + V_f of Di)

G-S Voltage : Over input voltage

D-S Current : Over I_{peak} at the section of output inductor

(4) Diode

It is recommended to use a schottky diode which satisfies followings and has low forward voltage drop and high switching speed.

Maximum current : Over maximum output current

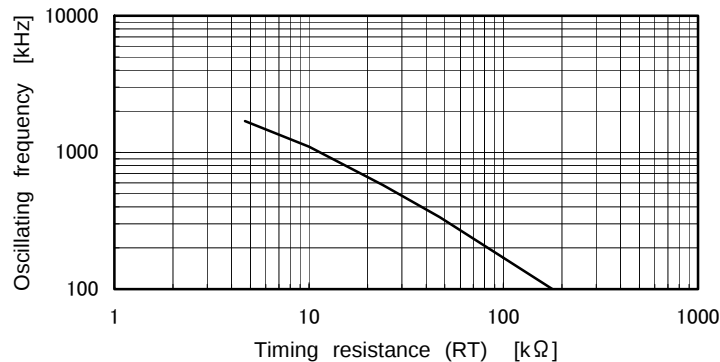
Direct reverse voltage : Over output voltage

* Please provide sufficient margin in the choice of external components by factoring into the worst case characteristics and temperature range.

(5) Setting the oscillator frequency

Refer to Fig.5 and determine Timing resistor (R_T) when setting the oscillating frequency.

Oscillating frequency vs. Timing resistance

Fig.8 Oscillating frequency – Timing resistance (R_T)

(6) Setting the output voltage

The output voltage is calculated by the following equation.

$$V_o = V_{INth} \cdot (R_1 + R_2) / R_2 \quad [V]$$

R₁, R₂ : Resistor divider network

V_{INth} : Error amp threshold voltage (typ.1V)

(but $V_o < V_{IN} \cdot 5$ because of MAXDUTY Min=80%)

(7) CTL/SS setting the soft start time

The time after CTL/SS is released before the output voltage starts to rise.

$$t(\text{start}) = C_{CTL} \cdot (V_{Do} - V_{off}) / I_{ss} \quad [S] \quad \text{approximated equation}$$

The time after the output voltage starts up before it reaches the specified output level.

$$t(\text{soft}) = C_{CTL} \cdot (V_{DUTY} - V_{Do}) / I_{ss} \quad [S] \quad \text{approximated equation}$$

$$V_{DUTY} = V_{Do} + 0.5 \cdot (1 - V_{IN} / V_{OUT}) \quad [V]$$

C_{CTL} : CTL/SS–GND capacitance V_{Do} : 0% duty threshold (Typ 1.6V) V_{off} : Output off CTL/SS voltage

I_{ss} : CTL/SS charge current (Typ 1μA) V_{DUTY} : stabilization operating ON duty.

●Timing chart

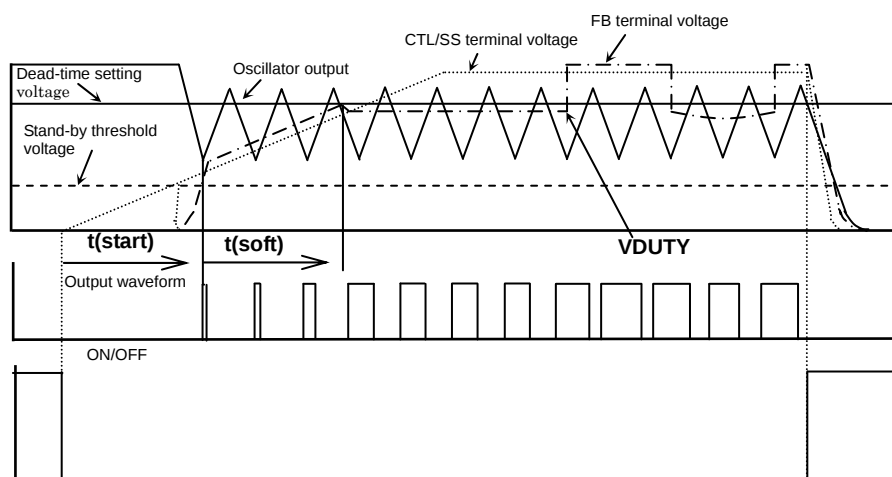
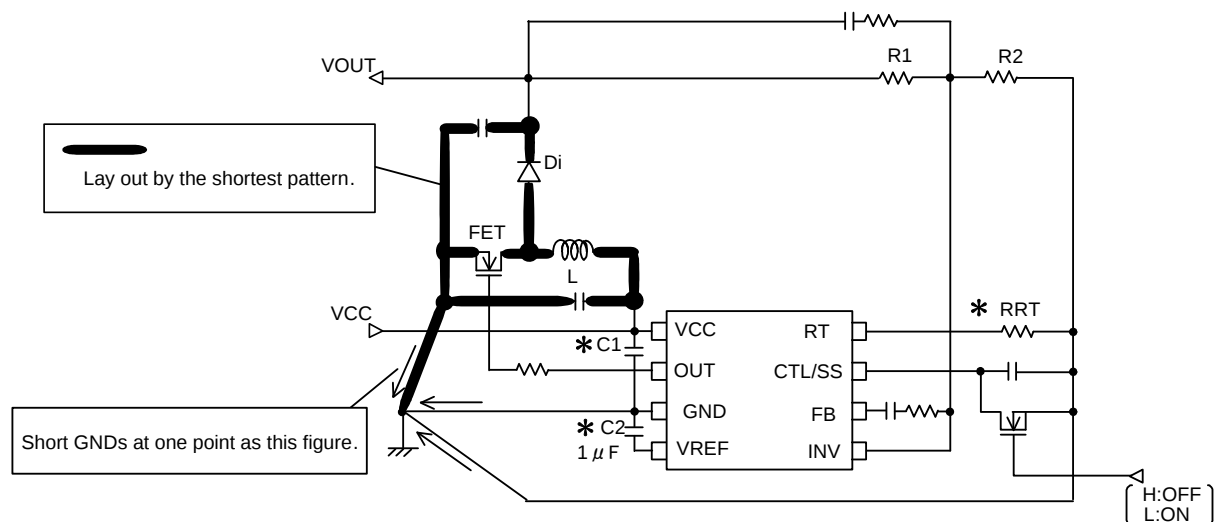


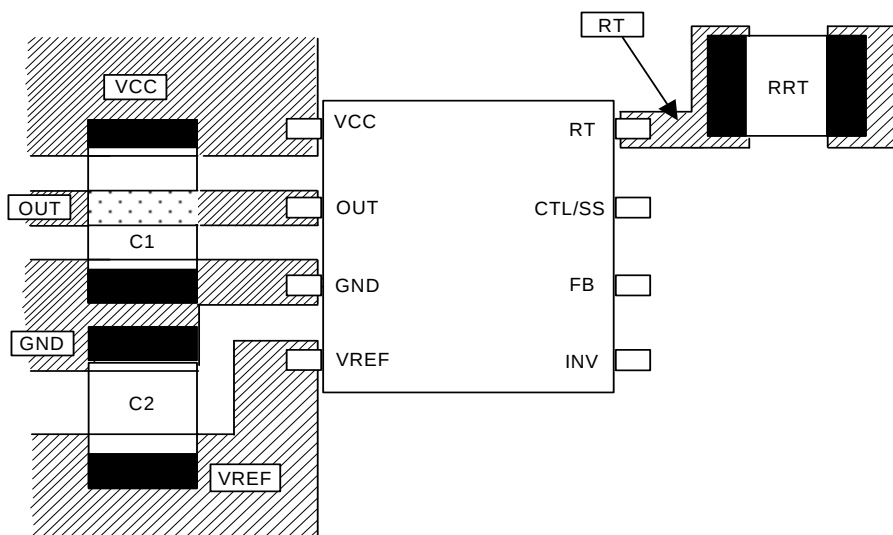
Fig.9

●Recommended board patterns



*Place these parts with attention about patterns shown in following Fig.7

Fig.10



C1 : Capacitor terminals have to be close enough to terminals of VCC and GND.

It is safe to pass OUT signal line under C1.

C2 : Capacitor terminals have to be close enough to terminals of VREF and GND.

R1 : Pattern area has to be small enough to reduce parasitic capacitance of RT terminal.

Fig.11 Recommended board patterns

● I/O Equivalent Circuit

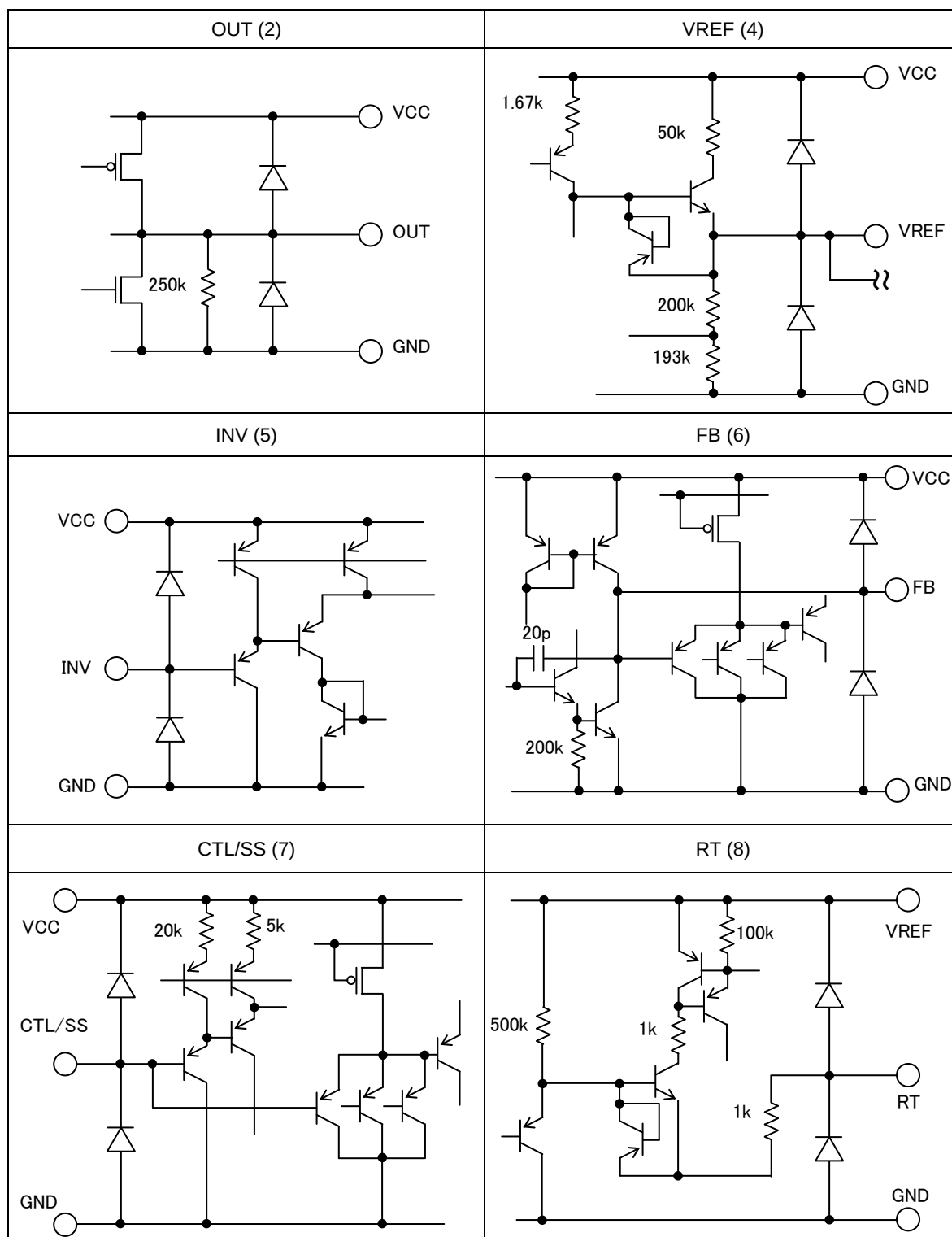


Fig.12

●Operation Notes

(1) Absolute maximum ratings

Use of the IC in excess of absolute maximum ratings such as the applied voltage or operating temperature range may result in IC deterioration or damage. Assumptions should not be made regarding the state of the IC (short mode or open mode) when such damage is suffered. A physical safety measure such as fuse should be implemented when use of the IC in a special mode where the absolute maximum ratings may be exceeded is anticipated.

(2) GND potential

Ensure a minimum GND pin potential in all operating conditions. In addition, ensure that no pins other than the GND pin. Carry a voltage lower than or equal to the GND pin, including during actual transient phenomena.

(3) Thermal design

Use a thermal design that allows for a sufficient margin in light of the power dissipation (P_d) in actual operating conditions.

(4) Inter-pin shorts and mounting errors

Use caution when orienting and positioning the IC for mounting on printed circuit boards. Improper mounting may result in damage to the IC. Shorts between output pins or between output pins and the power supply and GND pin caused by the presence of a foreign object may result in damage to the IC.

(5) Operation in a strong electromagnetic field

Use caution when using the IC in the presence of a strong electromagnetic field as doing so may cause the IC to malfunction.

(6) Thermal shutdown circuit (TSD circuit)

This IC incorporates a built-in thermal shutdown circuit (TSD circuit). The TSD circuit designed only to shut the IC off to prevent runaway thermal operation.

do not continue to use the IC after operating this circuit or use the IC in an environment where the operation of the thermal shutdown circuit is assumed.

(7) Testing on application boards

When testing the IC on an application board, connecting a capacitor to pin with low impedance subjects the IC to stress. Always discharge capacitors after each process or step. Ground the IC during assembly steps as an antistatic measure, and use similar caution when transporting or storing the IC. Always turn the IC's power supply off before connecting it to or removing it from a jig or fixture the inspection process.

(8) Common impedance

Power supply and ground wiring should reflect consideration of the need to lower common impedance and minimize ripple as much as possible (by making wiring as short and thick as possible or rejecting ripple by incorporating inductance and capacitance).

(9) Applications with modes that reverse VCC and pin potentials may cause damage to internal IC circuits.

For example, such damage might occur when VCC is shorted with the GND pin while an external capacitor is charged. It is recommended to insert a diode for preventing back current flow in series with VCC or bypass diodes between VCC and each pin.

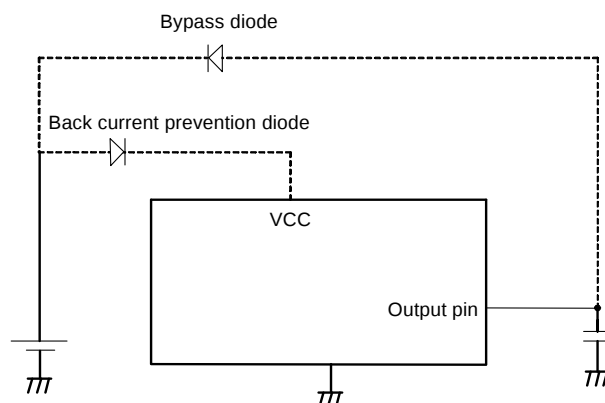


Fig.13

(10) Timing resistor

Timing resistor connected between RT and GND, has to be placed near RT terminal (8pin). And pattern has to be short Enough.

(11) IC pin input

This monolithic IC contains P + isolation and PCB layers between adjacent elements in order to keep them isolated. P/N junctions are formed at the intersection of these P layers with the N layers of other elements to create a variety of parasitic elements.

For example, when a resistor and transistor are connected to pins as shown in Fig.14,

○The P/N junction functions as a parasitic diode when $GND > (Pin A)$ for the resistor or $GND > (Pin B)$ for the transistor (NPN).

○Similarly, when $GND > (Pin B)$ for the transistor (NPN), the parasitic diode described above combines with the N layer of other adjacent elements to operate as a parasitic NPN transistor.

The formation of parasitic elements as a result of the relationships of the potentials of different pins is an inevitable result of the IC's architecture. The operation of parasitic elements can cause interference with circuit operation as well as IC malfunction and damage. For these reasons, it is necessary to use caution so that the IC is not used in a way that will trigger the operation of parasitic elements, such as by the application of voltage lower than the GND (PCB) voltage to input and output pins.

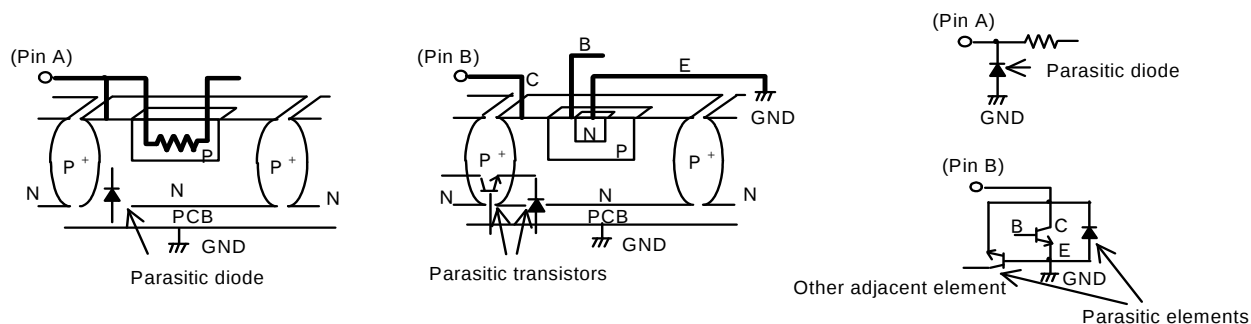
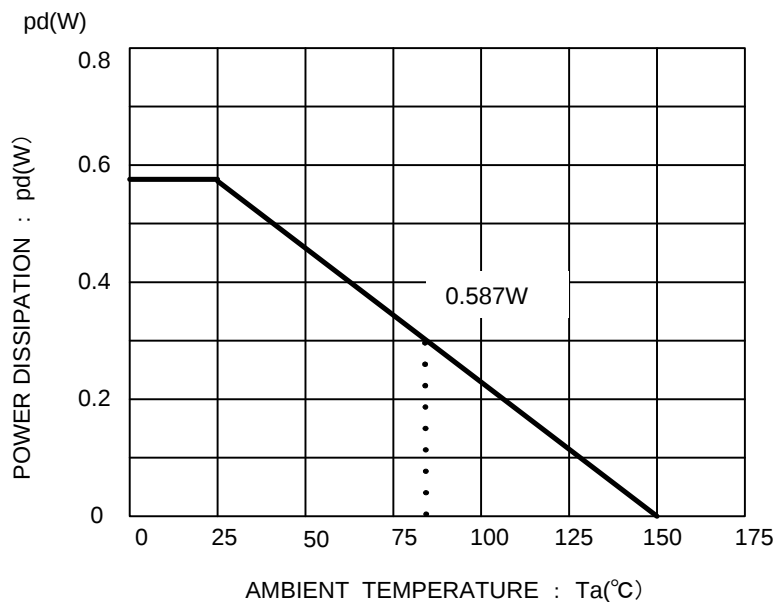


Fig.14

●Power Dissipation Reduction



IC mounted on a ROHM standard board (70mm x 70mm x 1.6mm, glass epoxy)

Fig.15

●Ordering part number

B	D
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Part No.

9	7	6	3
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Part No.

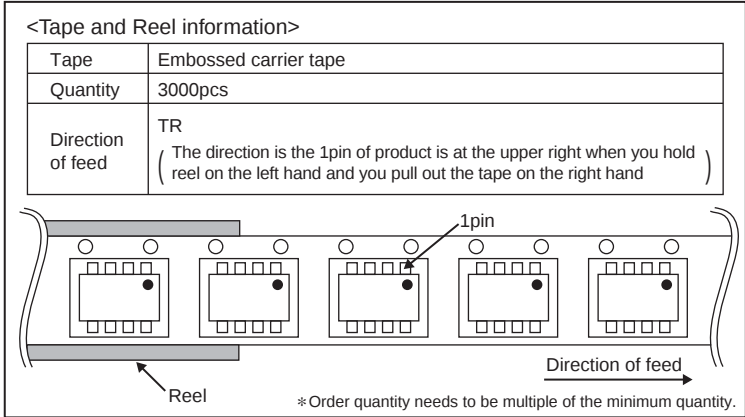
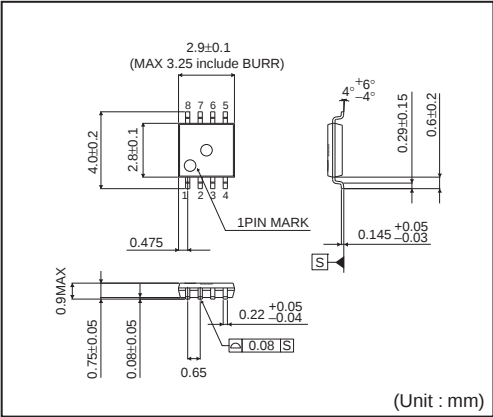
F	V	M
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Package
FVM: MSOP8

T	R
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Packaging and forming specification
TR: Embossed tape and reel
(MSOP8)

MSOP8



Notes

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